Product data sheet

1. General description

Ultrafast power diode in a SOT428 (DPAK) surface-mountable plastic package.

2. Features and benefits

- · High thermal cycling performance
- Low switching losses
- · Low thermal resistance
- Soft recovery minimizes power-consuming oscillations
- Surface-mountable package

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_R	reverse voltage	DC		-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3		-	-	5	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		-	-	60	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		-	-	66	А
Static characte	eristics						
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.12	1.3	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.97	1.11	V
Dynamic characteristics							
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	30	50	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K — A
2	K	cathode[1]	(7 B S)	001aaa020
3	Α	anode		
mb	К	cathode	DPAK (SOT428)	

[1] It is not possible to connect to pin 2 of the SOT428 package

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
BYV25D-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428				

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; T _{mb} ≤ 132 °C; square-wave pulse	-	10	Α
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; Fig. 4	-	60	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	66	Α
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

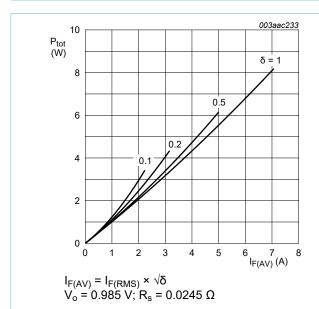


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

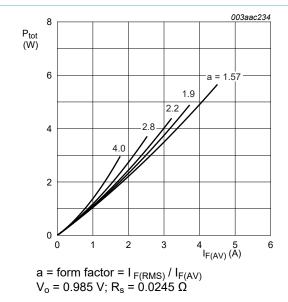
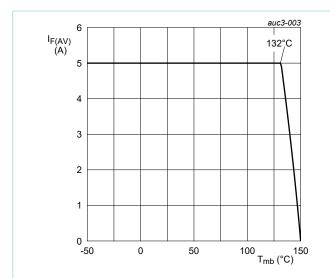


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

Product data sheet

WeEn Semiconductors BYV25D-600

Ultrafast power diode





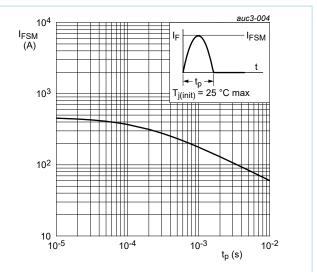


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5		-	-	3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air		[1]	-	50	-	K/W

[1] device mounted on an FR4 PCB, single-sided copper, tin plated and standard footprint

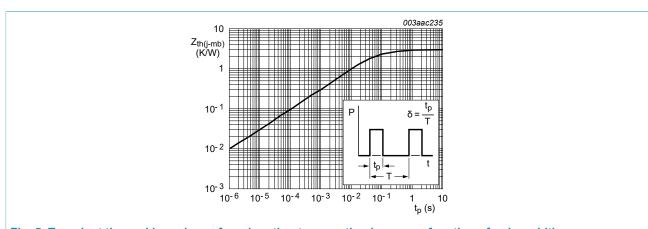
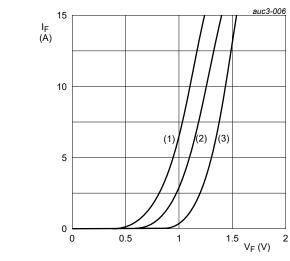


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse width

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V_{F}	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.12	1.3	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.97	1.11	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	2	50	μA
		V _R = 600 V; T _j = 100 °C	-	0.1	0.35	mA
Dynamic ch	naracteristics					,
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7	-	30	50	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	2.4	4	А
Q _r	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	30	50	nC
V_{FR}	forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}; T_j = 25 ^{\circ}\text{C}$	-	3.2	-	V



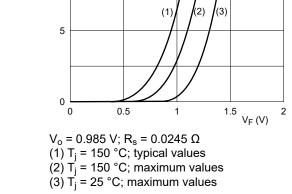
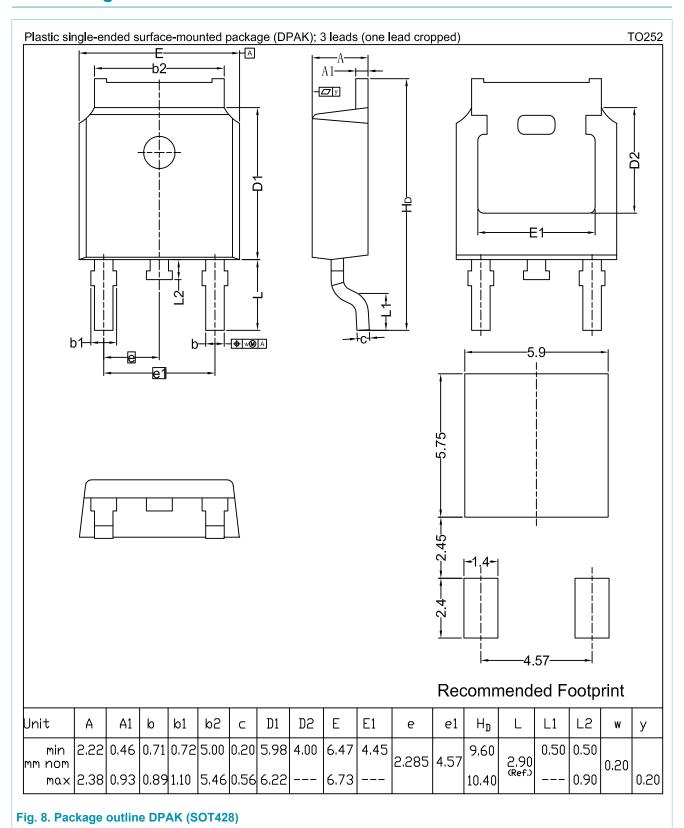


Fig. 6. Forward current as a function of forward voltage

 dI_F time 25 % 100 % I_R I_{RM} 003aac562

Fig. 7. Reverse recovery definitions; ramp recovery

10. Package outline



11. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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BYV25D-600

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